

INFORMATION DISCLOSURE CITATION
(Use several sheets if necessary)

Docket Number (Optional)
LEE.002

Application Number
NEW

Applicant(s)
Shone FUJA

Filing Date
January 5, 2004

Group Art Unit
To Be Assigned

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
DV	A	5,739,567	04/14/1998	WONG			
	B	5,770,514	06/23/1998	MATSUDA et al.			
	C	6,544,824	04/08/2003	PRADEEP et al.			
DV	D	6,365,452	04/02/2002	PERNG et al.			

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

DV	E	R. Muralidhar et al., "A 6V Embedded 90nm Silicon Nanocrystal Nonvolatile Memory", DigitalDNA Laboratories and the embedded Memory Center, 2003 IEEE, 4 pgs.
DV	F	B. De Salvo et al., "How far will Silicon nanocrystals push the scaling limits of NVMs technologies?", 2003 IEEE, 4 pgs.

EXAMINER *Phuland*

DATE CONSIDERED *07/06/05*

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.